# **Amplifier Transistor**

# **NPN Silicon**

#### **Features**

 These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CEO</sub>	25	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	40	Vdc
Emitter - Base Voltage	V <sub>EBO</sub>	4.0	Vdc
Collector Current — Continuous	I <sub>C</sub>	100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) @T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) @T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

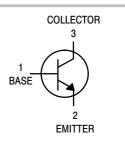
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.



# ON Semiconductor®

## http://onsemi.com





SOT-23 (TO -236) CASE 318-08 STYLE 6

#### **MARKING DIAGRAM**



RO = Specific Device Code

M = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location)
\*Date Code orientation and/or overbar may
vary depending upon manufacturing location.

# **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBT6521LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	<u>.</u>	•	•	•
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 0.5 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)</sub> CEO	25	-	Vdc
Emitter – Base Breakdown Voltage ( $I_E = 10 \mu Adc, I_C = 0$ )	V <sub>(BR)EBO</sub>	4.0	-	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 30 Vdc, I <sub>E</sub> = 0)	Ісво	-	0.5	μAdc
Emitter Cutoff Current $(V_{EB} = 5.0 \text{ Vdc}, I_C = 0)$	I <sub>EBO</sub>	-	10	nAdc
ON CHARACTERISTICS				
DC Current Gain $ \begin{pmatrix} I_C = 100 \ \mu Adc, \ V_{CE} = 10 \ Vdc \end{pmatrix} $ $ \begin{pmatrix} I_C = 2.0 \ mAdc, \ V_{CE} = 10 \ Vdc \end{pmatrix} $	h <sub>FE</sub>	150 300	- 600	-
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 50 mAdc, I <sub>B</sub> = 5.0 mAdc)	V <sub>CE(sat)</sub>	-	0.5	Vdc
SMALL-SIGNAL CHARACTERISTICS	<u>.</u>	•	•	•
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	-	3.5	pF
Noise Figure ( $I_C = 10 \mu Adc$ , $V_{CE} = 5.0 Vdc$ , Power Bandwidth = 15.7 kHz, 3.0 dB points @ = 10 Hz and 10 kHz)	NF	_	3.0	dB

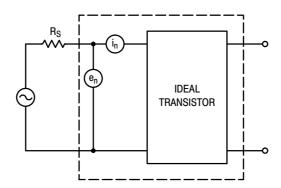


Figure 1. Transistor Noise Model

## **EQUIVALENT SWITCHING TIME TEST CIRCUITS**

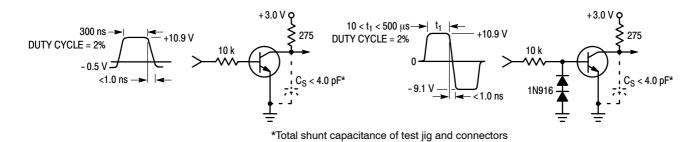


Figure 2. Turn-On Time

Figure 3. Turn-Off Time

## **TYPICAL NOISE CHARACTERISTICS**

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$ 

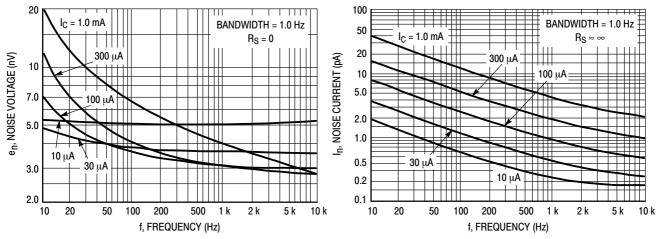


Figure 4. Noise Voltage

Figure 5. Noise Current

#### **NOISE FIGURE CONTOURS**

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$ 

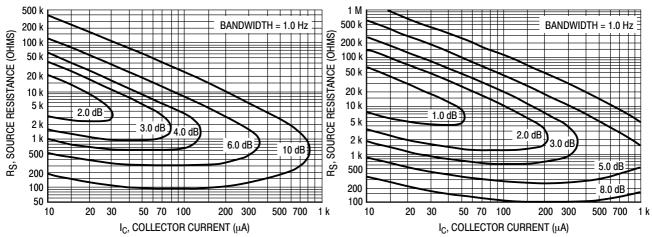
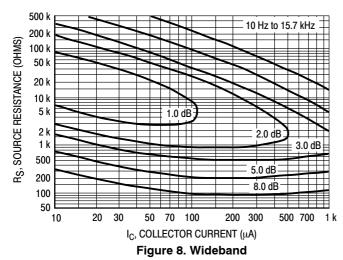


Figure 6. Narrow Band, 100 Hz

Figure 7. Narrow Band, 1.0 kHz



Noise Figure is defined as:

$$\text{NF} = 20 \log_{10} \left( \frac{e_{\text{n}}^2 + 4 \text{KTR}_S + I_{\text{n}}^2 R_S^2}{4 \text{KTR}_S} \right)^{1/2}$$

 $\boldsymbol{e}_{n}\,$  = Noise Voltage of the Transistor referred to the input. (Figure 3)

n = Noise Current of the Transistor referred to the input. (Figure 4)

 $\ddot{K}$  = Boltzman's Constant (1.38 x 10<sup>-23</sup> j/ $^{\circ}$ K)

T = Temperature of the Source Resistance (°K)

R<sub>S</sub> = Source Resistance (Ohms)

#### TYPICAL STATIC CHARACTERISTICS

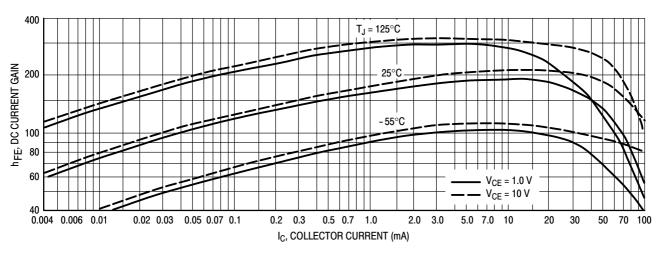


Figure 9. DC Current Gain

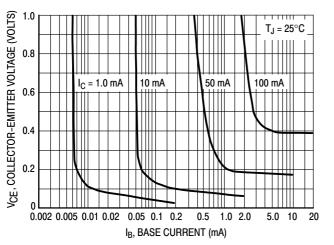


Figure 10. Collector Saturation Region

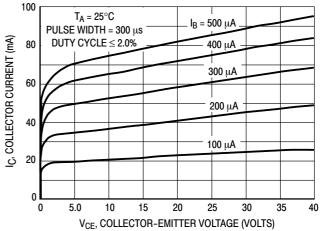


Figure 11. Collector Characteristics

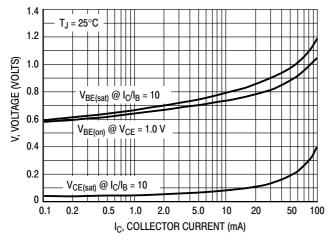


Figure 12. "On" Voltages

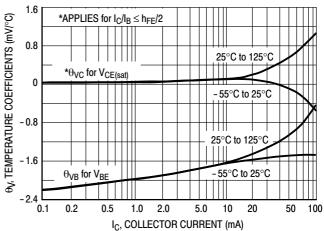
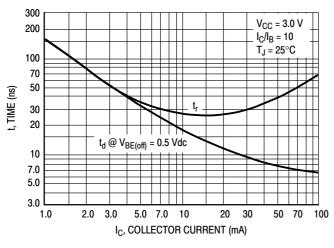


Figure 13. Temperature Coefficients

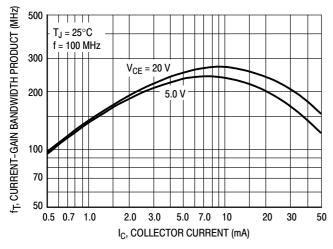
#### TYPICAL DYNAMIC CHARACTERISTICS



1000 700 500 300 200 t, TIME (ns) 100 70 50  $V_{CC} = 3.0 V$ 30  $I_{\rm C}/I_{\rm B}=10$ 20  $I_{B1} = I_{B2}$  $T_J = 25^{\circ}C$ 3.0 1.0 2.0 5.0 7.0 70 100 I<sub>C</sub>, COLLECTOR CURRENT (mA)

Figure 14. Turn-On Time

Figure 15. Turn-Off Time



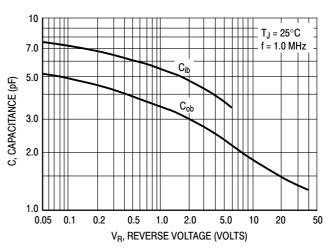
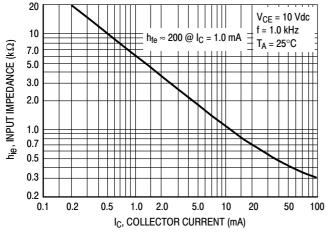


Figure 16. Current-Gain — Bandwidth Product

Figure 17. Capacitance



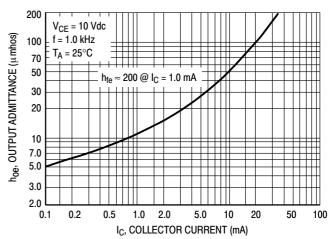


Figure 18. Input Impedance

Figure 19. Output Admittance

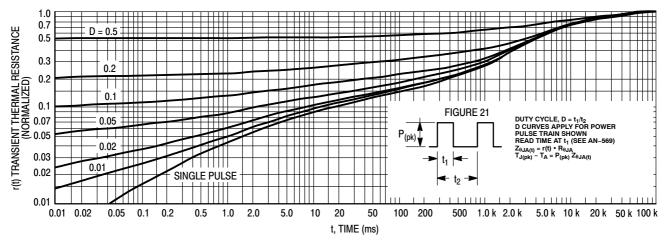


Figure 20. Thermal Response

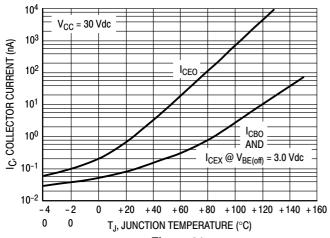


Figure 21.

# **DESIGN NOTE: USE OF THERMAL RESPONSE DATA**

A train of periodical power pulses can be represented by the model as shown in Figure 21. Using the model and the device thermal response the normalized effective transient thermal resistance of Figure 20 was calculated for various duty cycles.

To find  $Z_{\theta JA(t)}$ , multiply the value obtained from Figure 20 by the steady state value  $R_{\theta,JA}$ .

Example:

The MPS6521 is dissipating 2.0 watts peak under the following conditions:

$$t_1 = 1.0 \text{ ms}, t_2 = 5.0 \text{ ms}. (D = 0.2)$$

Using Figure 20 at a pulse width of 1.0 ms and D = 0.2, the reading of r(t) is 0.22.

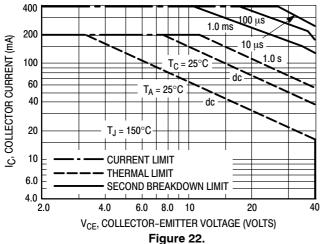
The peak rise in junction temperature is therefore

$$\Delta T = r(t) \times P_{(pk)} \times R_{\theta JA} = 0.22 \times 2.0 \times 200 = 88^{\circ} C.$$

For more information, see ON Semiconductor Application Note AN569/D, available from the Literature Distribution Center or on our website at www.onsemi.com.

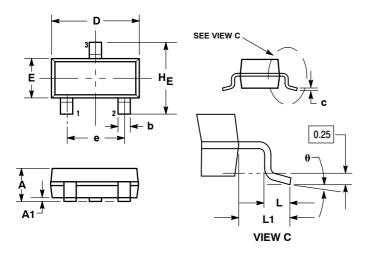
The safe operating area curves indicate I<sub>C</sub>-V<sub>CE</sub> limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 22 is based upon  $T_{J(pk)} = 150$ °C;  $T_C$  or T<sub>A</sub> is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided  $T_{J(pk)} \le 150$ °C.  $T_{J(pk)}$ may be calculated from the data in Figure 20. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN** 



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF
- BASE MATERIAL. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

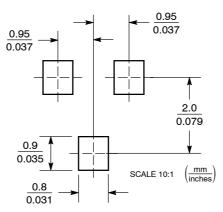
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

# STYLE 6:

PIN 1. BASE 2 EMITTER

COLLECTOR

## **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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